Peak gate current (t_p=20μs , T_j=150)	I_{GM}	4	A
Average gate power dissipation (T_j=150)	$P_{G(AV)}$	1	W
Peak gate power	P_{GM}	10	W
Peak pulse voltage (T_j=25 ; non-repetitive,off-state;FIG.7)	V_{pp}	0.5	kV

ELECTRICAL CHARACTERISTICS (T_j=25 unless otherwise specified)

Symbol	Test Condition	Value	Unit
		MIN.(T (T	

ORDERING INFORMATION

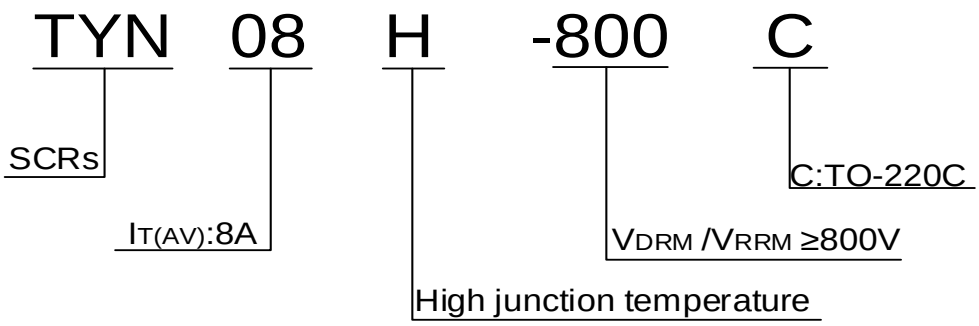
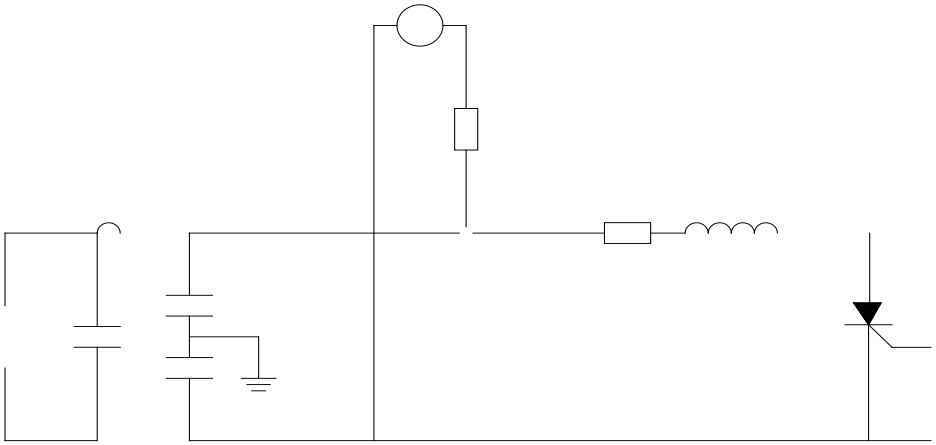


FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards.



TYN08H-800C **JieJie M**